



### 40V COMPLEMENTARY NPN-PNP SMALL SIGNAL TRANSISTOR IN SOT363

### **Features**

- Complementary Pair One 3904-Type NPN
  One 3906-Type PNP
- Ultra-Small Surface Mount Package
- Epitaxial Planar Die Construction
- Ideal for Low Power Amplification and Switching
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Datasheet (MMDT3946Q)

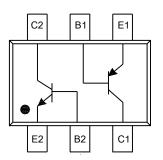
### **Mechanical Data**

- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Finish. Solderable per MIL-STD-202, Method 208 <sup>3</sup>
- Weight: 0.006 grams (Approximate)



**SOT363** 

Top View



E1, B1, C1 = PNP 3906 E2, B2, C2 = NPN 3904

Device Schematic and Pinout Top View

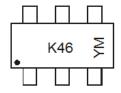
### Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
MMDT3946-7-F	AEC-Q101	K46	7	8	3,000
MMDT3946-7R-F	AEC-Q101	K46	7	8	3,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



K46 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: F = 2018) M = Month (ex: 9 = September)

Date Code Key

Year	2018		2019	2020		2021	2022		2023	2024		2025
Code	F		G	Н		[	J		K	L		M
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



## Absolute Maximum Ratings, NPN 3904 (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	60	V
Collector-Emitter Voltage	$V_{CEO}$	40	V
Emitter-Base Voltage	V <sub>EBO</sub>	6.0	V
Collector Current	I <sub>C</sub>	200	mA

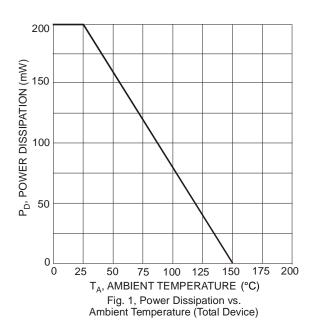
# Absolute Maximum Ratings, PNP 3906 (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-40	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-40	V
Emitter-Base Voltage	V <sub>EBO</sub>	-5.0	V
Collector Current	Ic	-200	mA

## Thermal Characteristics, Total Device (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	$P_{D}$	200	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	$R_{ hetaJA}$	625	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes: 5. For a device mounted on minimum recommended pad layout that is on a single-sided 0.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.





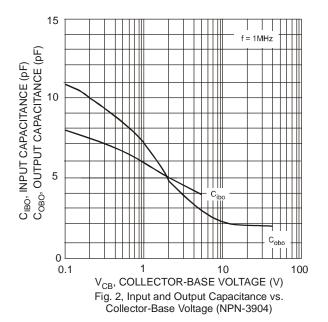
## Electrical Characteristics, NPN 3904 (@T<sub>A</sub> = +25°C, unless otherwise specified.)

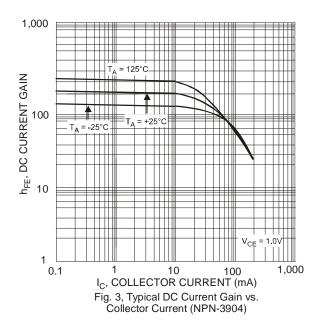
Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)					
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	60	_	V	$I_C = 10\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	40	_	V	$I_C = 1.0 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	6.0	_	V	$I_E = 10\mu A, I_C = 0$
Collector Cutoff Current	ICEX	_	50	nA	$V_{CE} = 30V, V_{EB(OFF)} = 3.0V$
Base Cutoff Current	I <sub>BL</sub>	_	50	nA	$V_{CE} = 30V, V_{EB(OFF)} = 3.0V$
ON CHARACTERISTICS (Note 6)					
Static Forward Current Transfer Ratio	h <sub>FE</sub>	40 70 100 60 30	300 — —	_	$\begin{split} I_C &= 100 \mu A, \ V_{CE} = 1.0 V \\ I_C &= 1.0 m A, \ V_{CE} = 1.0 V \\ I_C &= 10 m A, \ V_{CE} = 1.0 V \\ I_C &= 50 m A, \ V_{CE} = 1.0 V \\ I_C &= 100 m A, \ V_{CE} = 1.0 V \end{split}$
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>		0.20 0.30	V	$I_C = 10$ mA, $I_B = 1.0$ mA $I_C = 50$ mA, $I_B = 5.0$ mA
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	0.65	0.85 0.95	V	$I_C = 10$ mA, $I_B = 1.0$ mA $I_C = 50$ mA, $I_B = 5.0$ mA
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C <sub>obo</sub>	_	4.0	pF	$V_{CB} = 5.0V$ , $f = 1.0MHz$ , $I_E = 0$
Input Capacitance	C <sub>ibo</sub>	_	8.0	pF	$V_{EB} = 0.5V$ , $f = 1.0MHz$ , $I_C = 0$
Input Impedance	h <sub>ie</sub>	1.0	10	kΩ	
Voltage Feedback Ratio	h <sub>re</sub>	0.5	8.0	x 10 <sup>-4</sup>	V <sub>CE</sub> = 10V, I <sub>C</sub> = 1.0mA,
Small Signal Current Gain	h <sub>fe</sub>	100	400	_	f = 1.0kHz
Output Admittance	h <sub>oe</sub>	1.0	40	μS	
Current Gain-Bandwidth Product	f⊤	300	_	MHz	$V_{CE} = 20V$ , $I_C = 20mA$ , $f = 100MHz$
Noise Figure	NF		5.0	dB	$V_{CE} = 5.0V, I_{C} = 100\mu A,$ $R_{S} = 1.0k\Omega, f = 1.0kHz$
SWITCHING CHARACTERISTICS					
Delay Time	t <sub>d</sub>		35	ns	$V_{CC} = 3.0V, I_C = 10mA,$
Rise Time	t <sub>r</sub>	_	35	ns	$V_{BE(off)} = 0.5V, I_{B1} = 1.0mA$
Storage Time	ts		200	ns	V <sub>CC</sub> = 3.0V, I <sub>C</sub> = 10mA,
Fall Time	t <sub>f</sub>	_	50	ns	$I_{B1} = -I_{B2} = 1.0 \text{mA}$

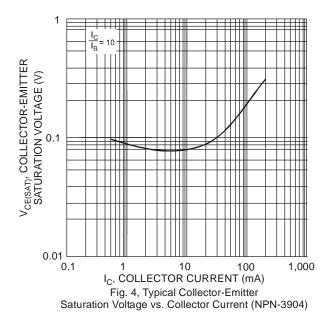
Notes: 6. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.

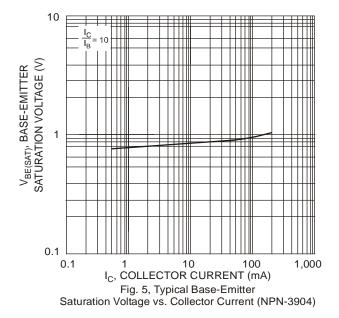


### Typical Electrical Characteristics, NPN 3904 (@TA = +25°C, unless otherwise specified.)











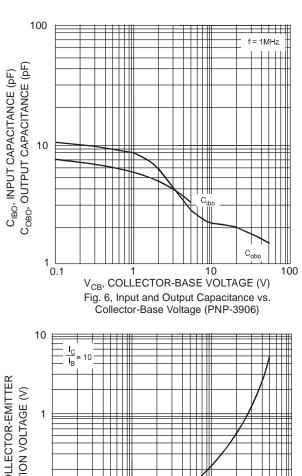
# Electrical Characteristics, PNP 3906 (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)					
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-40		V	$I_C = -10\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	-40		V	$I_C = -1.0 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-5.0	_	V	$I_E = -10\mu A, I_C = 0$
Collector Cutoff Current	I <sub>CEX</sub>	1	-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -3.0V$
Base Cutoff Current	$I_{BL}$	_	-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -3.0V$
ON CHARACTERISTICS (Note 6)					
Static Forward Current Transfer Ratio	h <sub>FE</sub>	60 80 100 60 30	300 — —	_	$\begin{split} I_C &= -100 \mu A,  V_{CE} = -1.0 V \\ I_C &= -1.0 m A,  V_{CE} = -1.0 V \\ I_C &= -10 m A,  V_{CE} = -1.0 V \\ I_C &= -50 m A,  V_{CE} = -1.0 V \\ I_C &= -100 m A,  V_{CE} = -1.0 V \end{split}$
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>		-0.25 -0.40	V	$I_C = -10$ mA, $I_B = -1.0$ mA $I_C = -50$ mA, $I_B = -5.0$ mA
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	-0.65 —	-0.85 -0.95	V	$I_C = -10\text{mA}, I_B = -1.0\text{mA}$ $I_C = -50\text{mA}, I_B = -5.0\text{mA}$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C <sub>obo</sub>	_	4.5	pF	$V_{CB} = -5.0V$ , $f = 1.0MHz$ , $I_E = 0$
Input Capacitance	$C_{ibo}$		10	pF	$V_{EB} = -0.5V$ , $f = 1.0MHz$ , $I_C = 0$
Input Impedance	h <sub>ie</sub>	2.0	12	kΩ	
Voltage Feedback Ratio	h <sub>re</sub>	0.1	10	x 10 <sup>-4</sup>	$V_{CE} = -10V, I_{C} = -1.0mA,$
Small Signal Current Gain	h <sub>fe</sub>	100	400		f = 1.0kHz
Output Admittance	h <sub>oe</sub>	3.0	60	μS	
Current Gain-Bandwidth Product	f⊤	250	_	MHz	$V_{CE} = -20V, I_{C} = -10mA,$ f = 100MHz
Noise Figure	NF	_	4.0	dB	$V_{CE} = -5.0V$ , $I_{C} = -100\mu A$ , $R_{S} = 1.0k\Omega$ , $f = 1.0kHz$
SWITCHING CHARACTERISTICS			•	•	•
Delay Time	t <sub>d</sub>		35	ns	V <sub>CC</sub> = -3.0V, I <sub>C</sub> = -10mA,
Rise Time	t <sub>r</sub>		35	ns	$V_{BE(off)} = -0.5V, I_{B1} = -1.0mA$
Storage Time	ts	_	225	ns	$V_{CC} = -3.0V, I_{C} = -10mA,$
Fall Time	t <sub>f</sub>	_	75	ns	$I_{B1} = -I_{B2} = -1.0 \text{mA}$

Notes: 6. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.



## Typical Electrical Characteristics, PNP 3906 (@T<sub>A</sub> = +25°C, unless otherwise specified.)



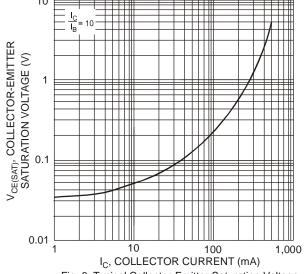
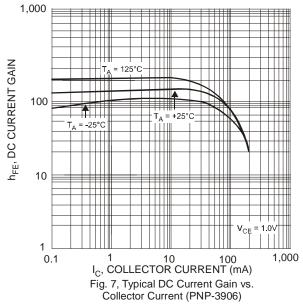
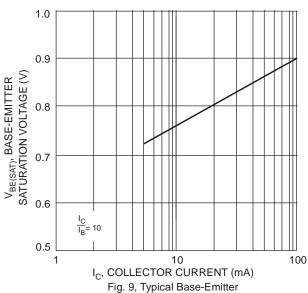


Fig. 8, Typical Collector-Emitter Saturation Voltage vs. Collector Current (PNP-3906)





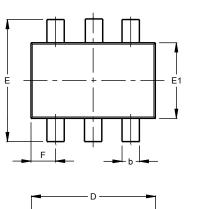
Saturation Voltage vs. Collector Current (PNP-3906)

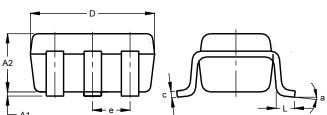
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# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.





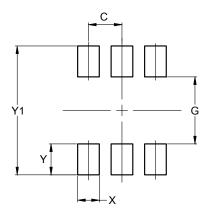
	SOT363							
Dim	Min	Max	Тур					
A1	0.00	0.10	0.05					
A2	0.90	1.00	0.95					
b	0.10	0.30	0.25					
C	0.10	0.22	0.11					
D	1.80	2.20	2.15					
Е	2.00	2.20	2.10					
E1	1.15	1.35	1.30					
е	C	.650 E	SC					
F	0.40	0.45	0.425					
L	0.25	0.40	0.30					
а	0°	8°						
All I	All Dimensions in mm							

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### **SOT363**

**SOT363** 



Dimensions	Value			
Dillielisiolis	(in mm)			
С	0.650			
G	1.300			
Х	0.420			
Y	0.600			
V1	2 500			



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  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
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